

JIEJIE MICROELECTRONICS CO., LTD.

Peak gate power	P_{GM}	2	W
Peak pulse voltage ($T_j=25$; non-repetitive,off-state;FIG.7)	V_{pp}	0.5	kV

NOTE 1: Operating junction temperature T_j is up to 125 when a resistor 1k is connected between Gate and Cathode. Without this resistor, the T_j is up to 110 only.

ELECTRICAL CHARACTERISTICS ($T_j=25$ unless otherwise specified)

Symbol	Test Condition	Value		Unit
		MIN.	TYP.	

JR0205H

 **JieJie Microelectronics Co., Ltd.**

ORDERING INFORMATION

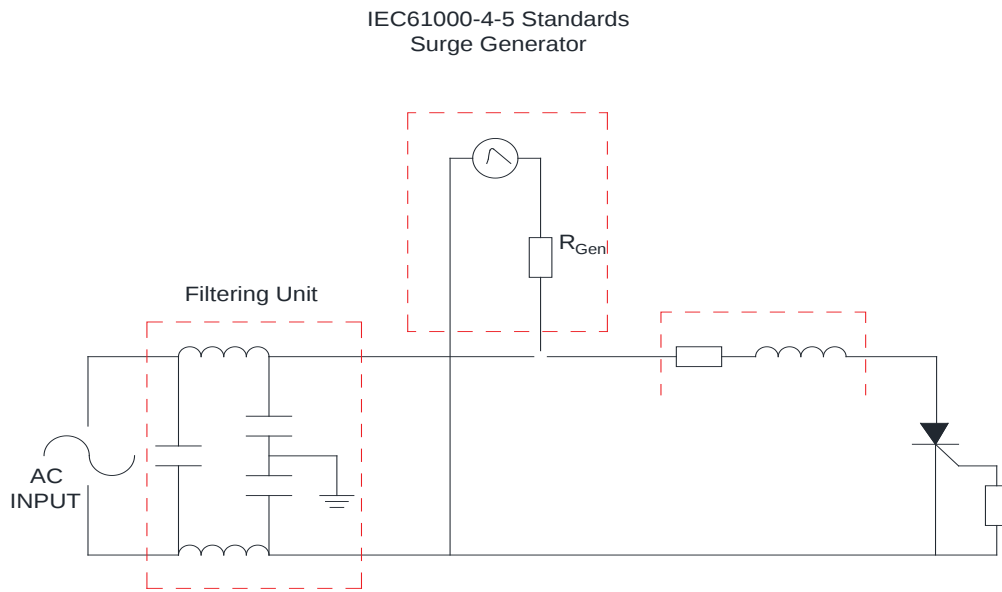
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FIG.1: Maximum power dissipation versus
RMS on-state current

FIG.2: RMS on-state current versus case
temperature

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



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